

# New Jersey Semi-Conductor Products, Inc.

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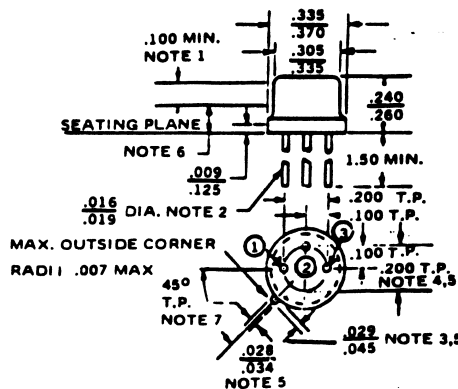
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## PARAMETERS

2N655  
 GE PNP LO-PWR BJT

Description: Ge PNP Lo-Pwr BJT

M11/High-Rel? (Y/N).....	
Vbr CBO.....	30
hfe.....	100
@Ic (A).....	10m
@VCE (test) (V).....	6.0
Ic Max. (A).....	250m
Trans. Freq (Hz) Min.....	
C(ob) (F).....	
Icbo Max. @Vcb Max. (A).....	15u
Vbr CEO.....	25
Max. PD (W).....	200m
Derate (Amb) (W/xC).....	2.6m
Oper. Temp (x C) Max.....	100u
Pkg Style.....	TO-5
Surface Mounted (Y/N).....	N
Pinout Equivalence Number.....	3-12



### TO5 NOTES:

1. This zone is controlled for automatic handling. The variation in actual diameter within the zone shall not exceed .010.
2. The specified lead diameter applies in the zone between .050 and .250 from the seating plane. Between .250 and 1.5 a maximum of .021 diameter is held. Outside of these zones the lead diameter is not controlled.
3. Measured from max. diameter of the actual device.
4. Leads having maximum diameter (.019) measured in gauging plane .054 ± .001 - .000 below the seating plane of the device shall be within .007 of their true locations relative to a maximum-width tab.
5. The device may be measured by direct methods or by the gauge and gauging procedure described on the base gauge drawing, GS-1.
6. Details of outline in this zone optional.
7. Tab centerline.



Quality Semi-Conductors